

FINAL REPORT

2019-10-01 - Rev. A

QEM-CCR-1908-00821 [029-NV356 /]

MOUSER ELECTRONICS

TI Device: TPS62260DRVT

QEM Report Number: QEM-CCR-1908-00821 Report Generated: 2019-10-01

| Customer Name: | MOUSER ELECTRONICS | Customer Contact: | Cody Strange |
|-----------------------------------|-----------------------|---------------------------|-------------------------|
| Customer Site: | | End Customer | GOEPEL electronic GmbH |
| Event Type / Origin of Detection: | Production / Assembly | Customer Contact(s) | cody.strange@mouser.com |
| RMA#/SCAR# | 029-NV356 | E-mail: | |
| Customer Tracking: | | | |
| Quantity of Received Unit(s): | 3 | TI P/N or Device Type: | TPS62260DRVT |
| Customer Notification Date: | 2019-08-23 | TI QEM Event: | QEM-CCR-1908-00821 |
| Current Action: | Closure | Unit Receive Date: | 2019-09-23 |
| | | | |

EXECUTIVE SUMMARY:

TI received 3 unit(s) of TI PN: TPS62260DRVT with customer provided issue description "SW pin of the IC behaves differently than the others with these faulty frequency and burst behavior. If you connect an oscillator, the course of the VOUT (short peaks up to 100mV) is not as stable as with the other ICs on a module".

TI electrical testing could not verify the customer reported issue and the customer return has been deemed **Trouble Not Identified (TNI)**.

Note: Abbreviations used in this report are listed in Appendix 2.

TEAM MEMBERS:

| TI Team Members | Process Role | Email |
|---------------------|--------------|-----------------|
| Goeswami Deva Singh | Event Owner | goeswami@ti.com |

DESCRIPTION OF NONCONFORMITY:

| Identification of TI's Material | | | | | | |
|---------------------------------|---------------------|---------|-------------------|------------------|-----------|----------|
| TI Part Number: | TPS62260DRVT | | | | | |
| Unit ID | Customer Unit ID | LTC | Assembly Lot # | Assembly Site | Fab Lot # | Fab Site |
| 1 | 1 | 84PEH7J | 8060976UT2 | UTAC | 7358048 | MIHO8 |
| 2 | 2 | 84PEH7J | 8060976UT2 | UTAC | 7358048 | MIHO8 |
| 3 | 3 | 84PEH7J | 8060976UT2 | UTAC | 7358048 | MIHO8 |

The following customer provided issue description was extracted from the information submitted by the customer with the returned TI devices and was entered into TI's Quality Event Management System (QEM):

Customer Issue Description:

QEM Report Number: QEM-CCR-1908-00821

Report Generated: 2019-10-01

Customer reported issue at: Production / Assembly

Issue type: Electrical | Issue type details: Web case CS0038479.

The number of failed parts is not known.

Background this is a DC/DC converter which works with a certain frequency / burst at an output voltage. I used the IC on 5 or more products.

Normally you can't see anything at the output voltage. With a DMM it corresponds to the expected value. But in this one application the voltage is measured indirectly via an ADC converter. There we have a tolerance of 50mV or so. At some point I noticed that the SW pin of the IC behaves differently than the others with these faulty frequency and burst behavior. If you connect an oscillator, the course of the VOUT (short peaks up to 100mV) is not as stable as with the other ICs on a module.

So I can't say how many faulty components are still noise through.

I also haven't looked at all the other modules to see if there are these problems as well. | Other details: Web case CS0038479.

The number of failed parts is not known.

Background this is a DC/DC converter which works with a certain frequency / burst at an output voltage. I used the IC on 5 or more products.

Normally you can't see anything at the output voltage. With a DMM it corresponds to the expected value. But in this one application the voltage is measured indirectly via an ADC converter. There we have a tolerance of 50mV or so. At some point I noticed that the SW pin of the IC behaves differently than the others with these faulty frequency and burst behavior. If you connect an oscillator, the course of the VOUT (short peaks up to 100mV) is not as stable as with the other ICs on a module.

So I can't say how many faulty components are still noise through.

I also haven't looked at all the other modules to see if there are these problems as well.

<u>Note:</u> Please see Appendix 1 for a copy of the customer provided information that accompanied the returned unit.

TI Issue Description:

CPR191030141

Unit passed bench verification and could not reproduce customer problem descripition.

Physical Verification Results

| Units | Pass/Fail | Description |
|-------|-----------|-------------|
| 1 | PASS | |
| 2 | PASS | |
| 3 | PASS | |

Curve Trace Verification Results

| Units | Pass/Fail | Description |
|-------|-----------|-------------------------------|
| 1 | PASS | ATE p2p and continuity passed |
| 2 | PASS | ATE p2p and continuity passed |
| 3 | PASS | ATE p2p and continuity passed |



Report Generated: 2019-10-01

• Bench Verification Results

| Units | Pass/Fail | Description | Sensitivity |
|-------|-----------|-------------|-------------|
| 1 | PASS | | |
| 2 | PASS | | |
| 3 | PASS | | |

IMPLEMENT AND VERIFY CONTAINMENT ACTIONS:

TI maintains an ongoing record of returns by lot number to track the number of returned TI devices for a single manufacturing lot.

TI has reviewed the return history for this unit's manufacturing lot and has not found evidence that this unit represents a sample of a larger, systemic issue with this particular production lot. Consequently, TI did not implement any additional containment actions for this production lot during initial investigation of the customer return.

The Lot Trace Code (LTC) marked on the unit(s) package can be decoded as following to the manufacturing date:

| Units | Lot Trace Code (LTC) | Manufacture Date |
|-------|----------------------|------------------|
| 1 | 84PEH7J | 2018/4 |
| 2 | 84PEH7J | 2018/4 |
| 3 | 84PEH7J | 2018/4 |

| Containment Actions Description | Owner(s) | Date |
|--|----------|------------|
| Review the return history of wafer fab lot(s) 7358048 | | |
| Results: The customer return history for this fab lot(s) did not indicate an abnormal risk for the customer reported issue on the returned unit. | Goes | 2019-09-23 |
| Review the lot history incl. test yield performance of assembly lot(s) 8060976UT2 | | |
| | Goes | 2019-09-23 |
| Results: No abnormalities were noted in the assembly lot(s) history that would indicate a systemic issue exists with this lot. | | |



DEFINE AND VERIFY ROOT CAUSE:

Verification Actions:

In order to determine root cause, the customer return was tested at TI to attempt to confirm the reported issue and the following was noted:

- Curve Trace Analysis
 - The TI device passed curve trace verification based on the ATE continuity and p2p leakage measurement
- Bench Analysis:
 Passed bench verification

Objective

SW pin behaves differently than others. Short VOUT peaks up to 100mV

No ATE result

Setup

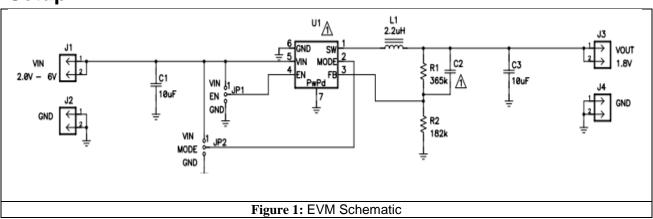


Table 1: EVM jumper setting

| J1 | 3.3V |
|-----|------|
| JP1 | VIN |
| JP2 | GND |
| J3 | 1.8V |



Measurements

- Load sweep at VOUT
- VOUT peak detect at PWM entry

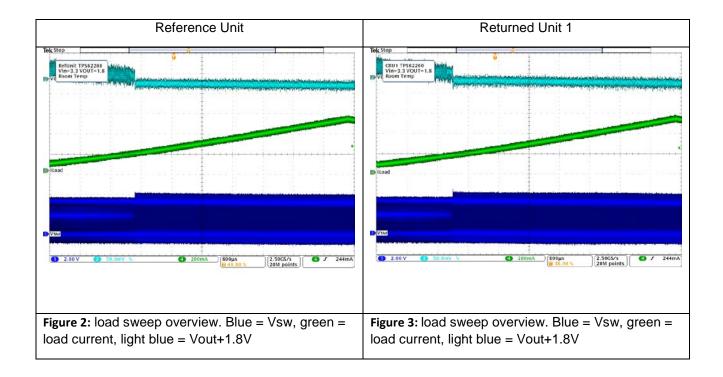
Results

Customer's issue could not be recreated. Device behaves as expected.

Load sweep at VOUT

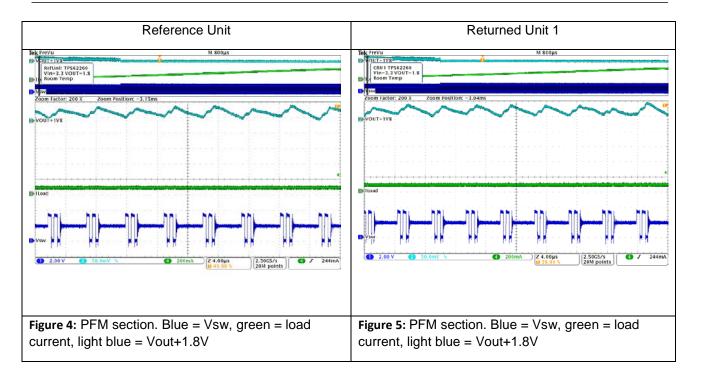
A reference Unit and the returned Unit 1 are measured at VIN = 3.3V, VOUT = 1.8V in auto mode.

The load current is ramped slowly from 10mA to 600mA in 8ms.

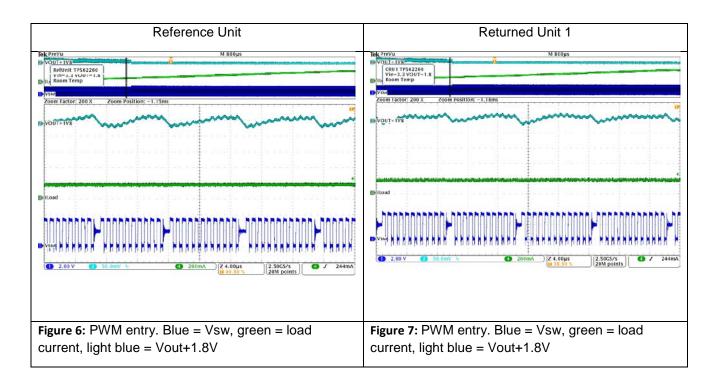


No abnormal behavior found in the overview. Reference Unit and returned Unit are working as expected.





No Observation in PFM mode.



No observation in PWM entry.



This measurement is done at cold and hot temperature as well. No observation there, too.

VOUT peak detect at PWM entry

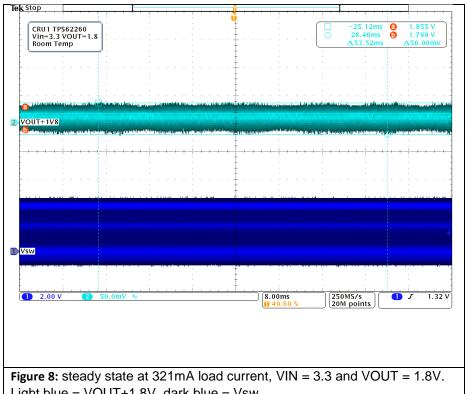
Worst case VOUT ripple is at PWM entry, this is measured over 80ms several times.

VIN = 3.3V

VOUT = 1.8V

Iload = 321mA

Max measured Vpp = ~55mV



Light blue = VOUT+1.8V, dark blue = Vsw.

In conclusion, TI could not verify the customer reported issue and the customer return has been deemed Trouble Not Identified (TNI).

If the customer can provide more details on the state of the TI device when the issue occurred, then TI can attempt additional testing. If requested, the TI device will be sent back to the customer.

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Appendix 1 (TI Notice and Disclaimer):

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Appendix 2 (TI Abbreviations):

| Abbreviation | Definition |
|--------------|---|
| | Eight Disciplines (8Ds) Problem Solving is a method developed at Ford Motor Company used to approach and to resolve problems. Its purpose is to |
| 8D | identify, correct, and eliminate recurring problems, and it is focused on product and process improvement. It establishes a permanent corrective action |
| | based on statistical analysis of the problem and on the origin of the problem by determining the root causes. |
| A/T | Assembly Test Site |
| A-B-A swap | The A-B-A swap method is used to investigate whether the observed issue is caused by non-TI part related aspects on the board. |
| ACO | Assembly County of Origin |
| AEO | Analog Engineering Operations |
| AFM | Atomic Force Microscope |
| AIZU | TI internal abbreviation for TI Aizu, Japan Wafer Fab |
| APC | Advanced Process Control |
| ASO | Assembly Site of Origin |
| ATE | Automated Test Equipment or Final Test |
| ATSS | Assembly Test Spec System |
| Batch # | Manufacturing Batch = SAP Batch number |
| BiCOM | Complementary Bi Polar |
| BCP | Business Continuity Program and Crisis Management |
| BOAC | Bond Over Active Circuit (BOAC) |
| C/T | Curve Tracer (C/T), a typical initial verification analysis measurement equipment for voltage vs. current curves |
| CA | Corrective action (CA): the action taken to help eliminate the root cause |
| CAPA | Corrective Action & Preventive Action |
| Carrier | Carrier is a pocket tape, tray, tube, or other fixture used to store and transport devices and components. |
| CCO | Chip County of Origin |
| CDA | Code for TI Chengdu, China Assembly Site |
| CDA | Compressed Dry Air |
| CDM | Charged Device Model (an ESD Test) |
| CFAB | TI internal abbreviation for TI Chengdu, China Wafer Fab |
| CIP | Continuous Improvement Process |
| CLARK | TI internal abbreviation for TI Pampanga (Clark), Philippines A/T Site |
| CMP | Chemical Mechanical Polishing |
| CMS | Change Management System |
| C00 | County of Origin |
| COP | Crystal Originated Particle(s) |
| COP | Customer Oriented Process |
| Cover Tape | Cover Tape is a clear or transparent tape |
| cpk | Capability Index-Centering |



| Abbrevietien | Definition |
|---|---|
| Abbreviation CPW | Definition Chips Per Wafer |
| CQE | Customer Quality Engineer |
| CRCT | Customer Return Cycle Time |
| CRU | Customer Returned Unit |
| CSO | Chip Site of Origin |
| CT CT, C/T | Cold Temperature Cycle Time |
| CU3 | Code for Tl Chengdu, China Wafer Fab |
| CU6 | Code for TI Malacca (Melaka), Malaysia A/T Site |
| CUA | Code for TI Maine (Portland), USA Wafer Fab |
| CV | Capacitance-Voltage Measurement |
| D/N | Chemical Vapor Deposition Delivery Note |
| DARC | Dielectric Anti-reflective Coating |
| DC | Datecode (D), typically shown on the TI box label in the format "YYWW" (year-year-week-week). |
| DDAO | TI Dallas Device Analysis Organization (Lab) |
| Desiccant | Desiccant is a moisture-adsorbing material placed inside sealed dry-pack bags to adsorb internal bag moisture. |
| DFAB Die | TI internal abbreviation for TI Dallas, USA Wafer Fab DFAB During this process, a wafer with up to thousands of circuits is cut into rectangular pieces, each called a Die. |
| DIP | Dual-In-Line Package |
| DIW | Deionized Water |
| DLN | Code for TI Dallas, USA Wafer Fab DFAB |
| DLS | Dynamic Laser Stimulation (DLS) can be used for failure isolation of functional failures dependent on voltage, temperature, frequency,using TTL |
| DM5 | input of XIVA. Code for TI Dallas, USA Wafer Fab DMOS5 |
| DM6 | Code for Ti Dallas, USA Wafer Fab DMOS6 |
| DMOS5 | TI internal abbreviation for TI Dallas, USA Wafer Fab DMOS5 |
| DMOS6 | TI internal abbreviation for TI Dallas, USA Wafer Fab DMOS6 |
| DOE | Design Of Experiment |
| DPPM DT | Defects Parts per Million Deep Trench |
| DUF | Diffusion under film |
| DUT | Device Under Test |
| DUV | Deep UV - (Stabilization of Resist) |
| ECN | Engineering Change Note |
| ECU EDX | Electrical Control Unit Energy Dispersive X-ray Spectroscopy (EDX) |
| EE | Equipment Engineering |
| EELS | Electron Energy Loss Spectroscopy |
| EFA | Electrical Failure Analysis |
| EIPD | Electrically Induced Physical Damage |
| EM | |
| | Electromigration (void formation) |
| EM | External Manufacturing |
| | |
| EM EMEA EMMI (PEM) EOL | External Manufacturing Europe Middle East and Africa (Sales Region) Photon Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector End of Life, same as Last Time Buy (LTB) |
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| EM EMEA EMMI (PEM) EOL EOS EPI E-pin ESD ESD ESD ESDAQ ETA EVM | External Manufacturing Europe Middle East and Africa (Sales Region) Photon Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector End of Life , same as Last Time Buy (LTB) Electrical Overstress Epitaxy Ejection Pin Electrostatic Discharge Estimated Shipping Date Enhanced Software Defect Analysis Eagle Test Automatic Test system Evaluation Module that allows users to evaluate the operation and performance of TI parts |
| EM EMEA EMMI (PEM) EOL EOS EPI E-pin ESD ESD ESDAQ ETA EVM FA | External Manufacturing Europe Middle East and Africa (Sales Region) Photon Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector End of Life , same as Last Time Buy (LTB) Electrical Overstress Epitaxy Ejetton Pin Electrostatic Discharge Estimated Shipping Date Enhanced Software Defect Analysis Eagle Test Automatic Test system Evaluation Module that allows users to evaluate the operation and performance of TI parts Failure Analysis |
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| EM EMEA EMMI (PEM) EOL EOS EPI E-pin ESD ESD ESDAQ ETA EVM FA FCT FDAO FFAB FIB FMEA FMX FQAE FT FTT FTTY GEC GF6 GF8 GFAB | External Manufacturing Europe Middle East and Africa (Sales Region) Photone Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector End of Life , same as Last Time Buy (LTB) Electrical Overstress Epitaxy Ejection Pin Electrostatic Discharge Estimated Shipping Date Enhanced Software Defect Analysis Eagle Test Automatic Test system Evaluation Module that allows users to evaluate the operation and performance of Ti parts Failure Analysis Functional Circuit Test Ti Freising Device Analysis Organization (Lab) Ti internal abbreviation for Ti Aguascalientes, Mexico A/T Site (FMX) Field Quality Application Engineer Final Test, usually the latest revision of the test program used in the A/T site. Fourier Transform Infrared Microscopy Final Test, Vield (after Packaging) Good Electrical Chip Code for Ti Greenock, Scotland Wafer Fab (8" = 200mm) Ti Internal abbreviation for Ti Greenock, Scotland Wafer Fab Ti Internal abbreviation for Ti Greenock, Scotland Wafer Fab Ti Internal abbreviation for Ti Greenock, Scotland Wafer Fab Ti Internal abbreviation for Ti Greenock, Scotland Wafer Fab |
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| EM EMEA EMMI (PEM) EOL EOS EPI E-pin ESD ESD ESDAQ ETA EVM FA FCT FDAO FFAB FIB FMEA FTY GEC GF6 GF8 GFAB GOI GRR GSP HBM | External Manufacturing Europe Middle East and Africa (Sales Region) Photon Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector End of Life , same as Last Time Buy (LTB) Electrical Overstress Epitaxy Ejection Pin Electrostatic Discharge Estimated Shipping Date Enhanced Software Defect Analysis Eagle Test Automatic Test system Evaluation Module that allows users to evaluate the operation and performance of TI parts Failure Analysis Functional Circuit Test TI Freising Device Analysis Organization (Lab) TI internal abbreviation for TI Freising, Germany Wafer Fab Focused lon Beam Failure Mode and Effects Analysis (FMEA) TI internal abbreviation for TI Aguascalientes, Mexico A/T Site (FMX) Field Quality Application Engineer Final Test, usually the latest revision of the test program used in the A/T site. Fourier Transform Infrared Microscopy Final Test Yield (after Packaging) Good Electrical Chip Code for TI Greenock, Scotland Wafer Fab (8" = 200mm) Ti internal abbreviation for TI Greenock, Scotland Wafer Fab (6" = 150mm) Code for TI Greenock, Scotland Wafer Fab (6" = 200mm) Ti internal abbreviation for TI Greenock, Scotland Wafer Fab (6seconded Sea Code Integrity) Gauge Reproducibility and Repeatability |
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| Abbreviation | Definition |
|------------------|---|
| ICT | In-Circuit Test |
| ILD | Inter Level Dielectric |
| ILD-n ILO | Inter Level Dielectric between Metal Levels n and n+1 Inter Level Oxide |
| IMD | Inter Lever Oxide Inter Metal Dielectric |
| IMDS | Inter-inetal Dielectric International Material Data System |
| IMPL | Implant |
| INQ | Inquiry |
| IPQC | In-Line Process control |
| IQC | Inline Quality Control |
| ITY | Integrated Test Yield |
| KGU | Known Good Unit |
| LBE | Local Business Entity |
| Lead-frame LL | Lead-frame insists as the interface area to the external terminals of the part. Lesson(s) Learned |
| LPCVD | Low Pressure Chemical-Vapor Deposition |
| LRR | Lot Reject Rate |
| LTB | Last Time Buy, same as End of Life (EOL) |
| LTC | Lot Trace Code; each TI part is marked with a unique LTC |
| LTO | Low Temperature Oxide (Oxidation) |
| MBB | Moisture Barrier Bag (MBB) or Dry Pack |
| MCLT | Minority Carrier Lifetime (TAU) |
| MCS | Metallurgic Cross-Section sample preparation is used to reveal the true component structure at a certain device location (e.g. solder joints, bond wire |
| MDAO | connection or die attach) TI Manchester Device Analysis Organization (Lab) |
| MEI | Manufacturing Equipment Installation |
| MES | Manuacturing Equipment installation Manufacturing Execution System Manufacturing Execution System |
| MEX | Manufacturing Excedution System Code for TI Aguascalientes, Mexico A/T Site (FMX) |
| MFAB | TI internal abbreviation for TI Main (Portland), USA Wafer Fab |
| MFC | Mass Flow Controller |
| MFF | Multi Factory Flow |
| MfG | Manufacturing |
| MH5 | Code for TI Miho, Japan Wafer Fab (5") |
| MH6 | Code for TI Miho, Japan Wafer Fab (6" = 150mm) |
| MH8 MIF | Code for TI Miho, Japan Wafer Fab (8" = 200mm) TI internal abbreviation for TI Miho, Japan Assembly Site |
| MIHO | Trimemar abbreviation for TI Miho, Japan Assembly Site Trintemar abbreviation for TI Miho, Japan Wafer Fab |
| MIM | Metal-Insulator-Metal |
| MLA | Code for Ti Kuala Lumpur, Malaysia A/T Site |
| MLO | Multi-Level Oxide |
| MM | Manufacturing Maintenance |
| MOCVD | Metal-organic Chemical Vapor Deposition |
| MOS | Metal Oxide Semiconductor Junction (Technology) |
| MOSFET | MOS Field Effect Transistor |
| MPY MRB | Multiprobe Yield Material Review Board |
| MSL | Maistria Review Board Moisture Sensitivity Level |
| | TI will conduct a background check on the device to determine whether case monitoring is sufficient. A non-actionable case (NAC) is a direct result of |
| NAC | this upfront background verification or physical analysis. |
| NMOS | N Channel Metal Oxide Semiconductor |
| NTF | No Trouble Found; TI could not verify the customer reported issue |
| NVA | Non-Value Added |
| O/S | Open / Shorts failures |
| OCAP | Out of Control Action Plan |
| OEE / OEU | Overall Equipment Efficiency / Overall Equipment Utilization Opportunities For Improvement |
| OFI OOC | Opportunities For Improvement Out of Control |
| 000 | Out of Spec |
| OPN | Operation Operation |
| PA | Preventive action |
| Pb-free | a product that is rated RoHS & high temperature solderable (260°C) compatible. |
| PCD | Process Control Document |
| PCN | Process/Product Change Notification |
| PDC | Product Distribution Center (warehouse) |
| PDN | Product Discontinue Notification (EOL) |
| PE PECVD | Process Engineer(ing) Plasma Enhanced Chemical Vapor Deposition |
| PECVD | Production Equipment Maintenance |
| PEM (EMMI) | Photon Emission Microscopy (EMMI / PEM) is a light sensing technique basically microscope with NIR objective lenses and a NIR detector |
| PFA PFA | Physical Failure Analysis |
| PFMEA | Process Failure Mode and Effects Analysis |
| PHI | Code for TI Baguio, Philippines A/T Site |
| PI | Polyimide |
| Pitch | The distance from pin to pin or inter-lead spacing. |
| Pizza Box | Intermediate container for the fully loaded reel, carrier tape, and cover tape |
| PMC | Preventive Maintenance |
| PMC PMD | Process Monitoring Chip Poly-Metal Dielectric(s) |
| PMOS | P Channel Metal Oxide Semiconductor |
| PO | r Chamilie wheat Oxide Semilicontotion Protective/Passivation Overcoating |
| PO | Purchase Order |
| POR | Process Of Record |
| PPAP | Production Part Approval Process (PPAP) |
| 1170 | |



| Abbreviation Definition PPB Parts Per Billion PPM Parts Per Million PRM Photo Resist Mask PSD P Implant Source/Drain PSG Phosphorous Silicate Glass PSOG Phosphorous Spin On Glass PSW Part Submission Warrant (PSW) PTN Product Termination Notification (PTN) | |
|--|-----------|
| PPM Parts Per Million PRM Photo Resist Mask PSD P Implant Source/Drain PSG Phosphorous Silicate Glass PSOG Phosphorous Spin On Glass PSW Part Submission Warrant (PSW) | |
| PRM Photo Resist Mask PSD P Implant Source/Drain PSG Phosphorous Silicate Glass PSOG Phosphorous Spin On Glass PSW Part Submission Warrant (PSW) | |
| PSD P Implant Source/Drain PSG Phosphorous Silicate Glass PSOG Phosphorous Spin On Glass PSW Part Submission Warrant (PSW) | |
| PSG Phosphorous Silicate Glass PSOG Phosphorous Spin On Glass PSW Part Submission Warrant (PSW) | |
| PSW Part Submission Warrant (PSW) | |
| | |
| PTN Product Termination Notification (PTN) | |
| | |
| PVD Physical Vapor Deposition | |
| QA Quality Assurance | |
| QAB Code for TI Pampanga (Clark), Philippines A/T Site QBD Charge to Breakdown | |
| QBS Qualification by Similarity | |
| QC Quality Control | |
| QEM Quality Event Manager system for 8D reports | |
| QLT Quality Leadership Team | |
| QRA Quality & Reliability Assurance | |
| QSS Quality System Standard | |
| QST Quality Steering Team | |
| QTY Quantity | |
| RC Root Cause | |
| REB Resist Etch Back | |
| RFAB TI internal abbreviation for TI Richardson, USA Wafer Fab RFB Code for TI Richardson, USA Wafer Fab | |
| ROHS Restriction of Hazardous Substances Directive 2002/95/EC | |
| NOTS RESTRICTION IN FRAZIONALES DIRECTIVE 2002/93/EC RPN Risk Potential Number | |
| RPPM Returned Parts per Million | |
| RT Room Temperature | |
| RTA Rapid Thermal Anneal | |
| RTM Release to market | |
| RTO Rapid Thermal Oxidation | |
| RTP Rapid Thermal Processing | |
| RTV Ramp to Volume | |
| SACVD Sub-Atmospheric Chemical - Vapor Deposition | |
| SAM Scanning Acoustic Microscopy; using ultrasonic waves to check for delamination. SBE Strategic Business Entity | |
| SDL Stategic Districts SCI Sub Collector Implant | |
| SCM Scanning Capacitance Microscopy | |
| SCR Standard Change Request | |
| Scribe Line Thin non-functional spacing is between neighboring Dies on a wafer where a saw can safely cut the wafer without damaging the | circuits. |
| SD Source-Drain (NSD,PSD) | |
| SEM Scanning Electron Microscope; imaging defects / damages beyond the resolution of an optical microscope | |
| SFAB TI internal abbreviation for TI Sherman, USA Wafer Fab | |
| SFC Statistical Factory Control | |
| ShDAO Ti Shanghai Device Analysis Organization (Lab) | |
| SHE Code for TI Sherman, USA Wafer Fab Shelf Life Length of time that a TI part may be stored in controlled environment before mounted onto applications. | |
| SIMS Secondary Ion Mass Spectroscopy | |
| SMC Statistic Machine Control or Scribe line Monitoring Chip | |
| SMD Surface Mount Device | |
| SMIF Standard Mechanical Interface | |
| sMPY Standardized Multiprobe Yield | |
| SMS Semiconductor Manufacturing System | |
| SO Sales Order | |
| SOF State of Finish | |
| SOG Spin on Glass SDC Statistical Process Control | |
| SPC Statistical Process Control | |
| Spreading Resistance Prope | |
| SRP Spreading Resistance Probe SS Sample Size | |
| SRP Spreading Resistance Probe SS Sample Size STC Unique tracking number on the TI label (1T) for each shipping container. | |
| SS Sample Size STC Unique tracking number on the TI label (1T) for each shipping container. STI Shallow Trench isolation | |
| SS Sample Size STC Unique tracking number on the TI label (1T) for each shipping container. STI Shallow Trench isolation STM Scanning Tunneling Microscope (Microscopy) | |
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| Abbreviation | Definition |
|--------------|--|
| TNI | Trouble Not Identified; TI's investigation does not confirm the customer problem. |
| UPW | Ultra-Pure water |
| V/I | Voltage (V) vs. Current (I) verification |
| Via-n | Connection between Metal Levels n and n+1 |
| VPD | Vapor Phase Decomposition |
| VPO | Versaport Pod Opener |
| VTN | Voltage Threshold N |
| VTP | Voltage Threshold P |
| W/F | Wafer Fab |
| WEE | Wafer Edge Exposure |
| WIC | Workplace Inventory Control |
| WIP | Work In Process |
| WLP | Wafer Level Package |
| WLR | Wafer Level Reliability |
| XIVA (LSIM) | Laser Signal Injection Microscopy (LSIM) is a current sensing technique Externally Induced Voltage Alterations |
| X-RAY | Electromagnetic radiation that differentially penetrates structures and creates images of these structures on photographic film or a fluorescent screen. These images are called diagnostic x rays. |
| YE | Yield Enhancement |

Appendix 3 (Customer Report Info):

| Type of Customer Information available | |
|---|--|
| TI part level issue description | |
| Conditions of non-conformance (e.g. Voltage, Current, Input Conditions, etc.) | |
| Measurements / Datalogs | |
| Environmental temperature at time the issue was observed | |
| Crosscheck (A-B-A swap) | |
| Sporadic or Reproducible | |
| Pictures | |
| Schematic | |

(Please complete the above table if needed and embed below a screen shot of customer complaint file)